



20V Dual N-Channel Enhancement Mode MOSFET - ESD Protected

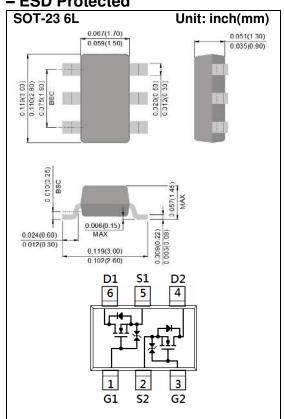
Voltage 20 V Current 2 A

Features

- RDS(ON), VGS@4.5V, ID@2.0A<150mΩ
- RDS(ON) , VGS@2.5V, ID@1.5A<215mΩ
- RDS(ON), VGS@1.8V, ID@0.5A<400mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: SOT-23 6L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.0141 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETE	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	20	V
Gate-Source Voltage		V _{GS}	<u>+</u> 8	V
Continuous Drain Current		I _D	2	Α
Pulsed Drain Current ^(Note 4)		I _{DM}	8	Α
Power Dissipation	T _a =25°C	P _D	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C
Typical Thermal Resistance - Junction to Ambient ^(Note 3)		R _{0JA}	100	°C/W





Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	20	-	-	V	
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	0.5	0.8	1.0	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =2.0A	-	105	150		
		V _{GS} =2.5V, I _D =1.5A	-	150	215	mΩ	
		V _{GS} =1.8V, I _D =0.5A	-	250	400		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V	-	0.01	1	uA	
Gate-Source Leakage Current	Igss	$V_{GS}=\underline{+}8V, V_{DS}=0V$	-	<u>+</u> 2	<u>+</u> 10	uA	
Dynamic ^(Note 5)							
Total Gate Charge	Q_g	V 40V I 0A	-	1.8	-	nC	
Gate-Source Charge	Q _{gs}	V _{DS} =10V, I _D =2A, V _{GS} =4.5V ^(Note 1,2)	-	0.4	-		
Gate-Drain Charge	Q_{gd}	VGS=4.5V(Note 1,2)	-	0.45	-		
Input Capacitance	Ciss		-	92	-	pF	
Output Capacitance	Coss	V _{DS} =10V, V _{GS} =0V, f=1.0MHZ	-	25	-		
Reverse Transfer Capacitance	Crss	I=1.UIVITZ	-	9.1	-		
Turn-On Delay Time	td _(on)	101/ 1 04	-	6.5	-		
Turn-On Rise Time	tr	V _{DD} =10V, I _D =2A,	-	26.5	-	ns	
Turn-Off Delay Time	td _(off)	$V_{GS}=4.5V$, $R_{G}=6\Omega^{(Note~1,2)}$	-	43	-		
Turn-Off Fall Time	tf	MG=012(Note 1,2)	-	34	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	l-		-	-	1.6	А	
Diode Forward Current	ls						
Diode Forward Voltage	V _{SD}	I _S =1.6A, V _{GS} =0V	-	0.9	1.2	V	

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

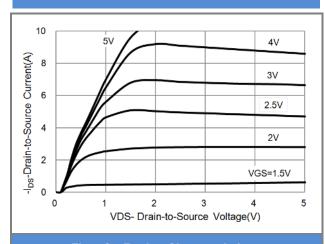


Fig.1 On-Region Characteristics

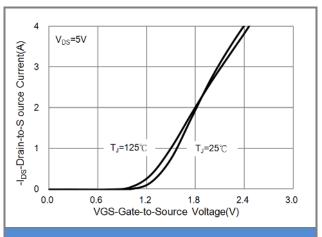


Fig.2 Transfer Characteristics

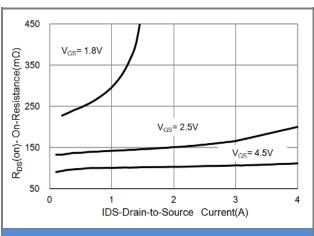


Fig.3 On-Resistance vs. Drain Current

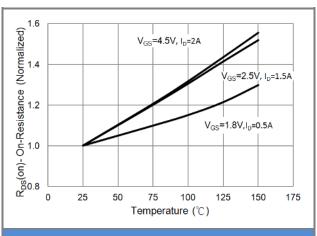
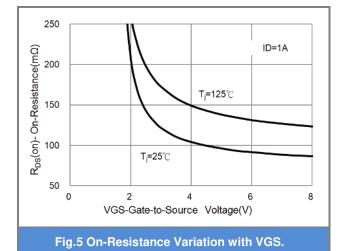
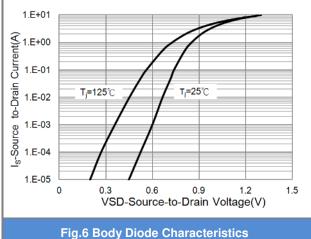


Fig.4 On-Resistance vs. Junction temperature









TYPICAL CHARACTERISTIC CURVES

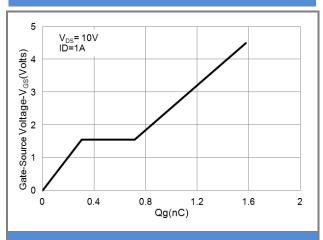


Fig.7 Gate-Charge Characteristics

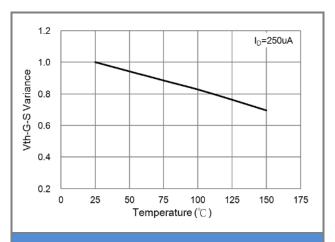


Fig.8 Threshold Voltage Variation with Temperature.

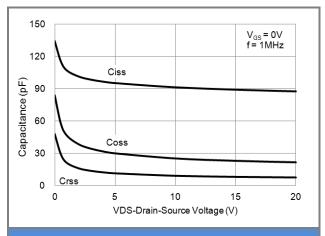


Fig.9 Capacitance vs. Drain-Source Voltage.

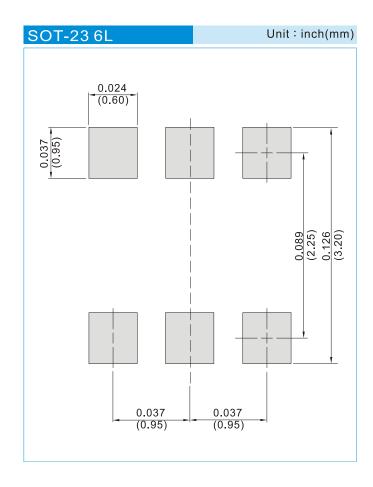




Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJS6830_S1_00001	SOT-23 6L	3K pcs / 7" reel	SG0	Halogen free RoHS compliant

Mounting Pad Layout







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